CSP16C04/CSB16C04



PRELIMINARY

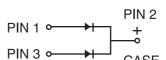
16 AMPS, SCHOTTKY BARRIER RECTIFIERS

FEATURES

- Metal of silicon rectifier, major carrier conduction
- Low power loss. high efficient
- High current capability, low VF







MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

(Tc=25°C unless otherwise noted)

Parameter	Symbol	Limit	Unit
Maximum Recurrent Peak Voltage	VRRM	40	٧
Maximum RMS Voltage	VRMS	28	٧
Maximum DC Blocking Voltage	VDC	40	٧
Maximum Average Forward Rectified Current at Tc=95°C	I F(AV)	16	А
Peak Forward SurgeCurrent, 8.3ms single half sine- wave superimposed on rated load (JEDEC Method)	I FSM	250	A
Maximum Forward Voltage a IF=8A, Tc=25°C	VF	0.62	V
Maximum Reverse Current at Peak Reverse Voltage ^a	l _R	0.5	mA
Typical Thermal Resistance, Junction-to-Case	$R_{ heta}$ JC	3	°C/W
Typical Junction Capacitance, VR=4V	CJ	700	pF
Maximum Operating Junction Temperature	TJ	-65 to 125	°C
Maximum Storage Temperature	Tstg	-65 to 150	°C

NOTEE:a. Test Pulse Width 300us, Duty Cyale 2%

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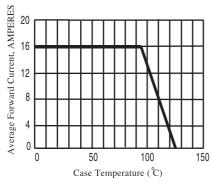


Figure 1. Forward Current Derating Curve

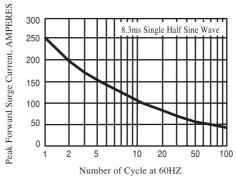
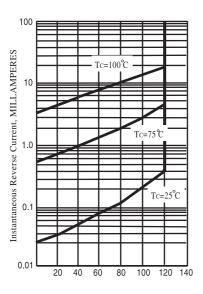
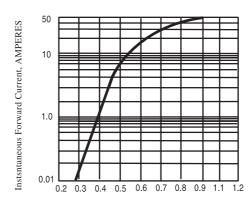


Figure 3. Maximum Non-Repetitive Surge Current



Percent of Rated Voltage Peak Reverse Voltage

Figure 2. Typical Reverse Characteristics



Instantaneous Forward Voltage (V)

Figure 4. Typical Instantaneous Forward Characteristics

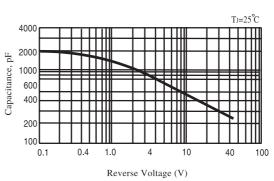


Figure 5. Typical Junction Capacitance